Docket No.: 2336-257 **PATENT**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of **EXPEDITED PROCEDURE**

Response under 37 CFR 1.116

Seung Wan CHAE et al.

U.S. Patent Application No. 10/811,808 Confirmation No. 2845

Group Art Unit: 2814

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DIODE entre la mil For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE

AND METHOD FOR MANUFACTURING THE SAME

REQUEST FOR RECONSIDERATION

COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria VA 22313-1450

Sir:

This paper is submitted in reply to the Office Action mailed March 8, 2006, which was made Final.